# NSN 5961-01-086-9194

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Inclosure Material:

Metal

**Overall Length:** 

0.450 inches

## **Overall Diameter:**

0.875 inches

#### Mounting Facility Quantity:

2

#### Internal Configuration:

Junction contact

Joint Electronic Device Engineering Council/jedec/case Outline Designation:

#### To-3

Electrode Internally-electrically Connected To Case:

Collector

**Mounting Method:** 

# Unthreaded hole

**Features Provided:** 

Hermetically sealed case

#### Semiconductor Material:

Silicon

# Voltage Rating In Volts Per Characteristic:

80.0 breakdown voltage, collector-to-base, emitter open and 80.0 breakdown voltage, collector-to-emitter, base open and 5.0 breakdown voltage, emitter-to-base, collector open

#### **Current Rating Per Characteristic:**

Between 100.00 milliamperes source cutoff current and 8.00 amperes source cutoff current

#### **Power Rating Per Characteristic:**

90.0 watts small-signal input power, common-collector

### Maximum Operating Tempurature Per Measurement Point:

200.0 degrees celsius junction

#### **Special Features:**

Junction pattern arrangement: npn

#### **Terminal Type And Quantity:**

1 case and 2 pin

#### Shelf Life:

N/a

#### Unit Of Measure:

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#### Demilitarization:

No

#### Fiig:

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